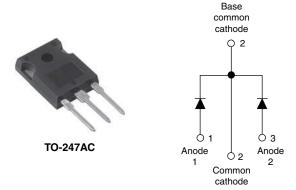


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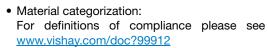
# Hyperfast Rectifier, 2 x 30 A FRED Pt®



PRODUCT SUMMARY					
Package	TO-247AC				
I <sub>F(AV)</sub>	2 x 30 A				
$V_{R}$	300 V				
V <sub>F</sub> at I <sub>F</sub>	1.25 V				
t <sub>rr</sub> typ.	See Recovery table				
T <sub>J</sub> max.	175 °C				
Diode variation	Common cathode				

#### **FEATURES**

- Hyperfast recovery time
- Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature
- Designed and qualified according to JEDEC-JESD47







ROHS
COMPLIANT
HALOGEN
FREE
Available

### **DESCRIPTIONS/APPLICATIONS**

VS-60CPH03PbF, VS-60CPH03-N3 series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Repetitive peak reverse voltage	$V_{RRM}$		300	V			
per leg		T <sub>C</sub> = 143 °C	30				
Average rectified forward current total device	I <sub>F(AV)</sub>	1 <sub>C</sub> = 143	60	Α			
Non-repetitive peak surge current per leg	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	300				
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS MIN. TYP.				UNITS		
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	300	-	-			
Forward voltage	V	I <sub>F</sub> = 30 A	-	1.08	1.25	V		
	V <sub>F</sub>	I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C	-	0.92	1.00			
Deverage leakens augment		V <sub>R</sub> = V <sub>R</sub> rated	-	0.05	60			
Reverse leakage current I <sub>R</sub>		T <sub>J</sub> = 125 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	20	300	μΑ		
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 300 V	=	70	-	pF		
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	ı	3.5	-	nH		



# VS-60CPH03PbF, VS-60CPH03-N3

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST C	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, dI_F/dt = 3$	$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	55		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 30 A dI <sub>F</sub> /dt = - 200 A/μs V <sub>R</sub> = 200 V	-	39	-	ns	
		T <sub>J</sub> = 125 °C		-	57	-		
Dook recovery overent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	2.8	-	Α	
Peak recovery current		T <sub>J</sub> = 125 °C		-	7.5	-	_ ^	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	55	-	200	
		T <sub>J</sub> = 125 °C		-	214	=	nC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65	-	175	°C		
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	0.5	0.9			
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>	R <sub>thJA</sub> Typical socket mount		-	40	°C/W		
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.4	-			
Weight			-	6.0	-	g		
vveignt			-	0.22	-	OZ.		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Marking device		Case style TO-247AC	60CPH03					



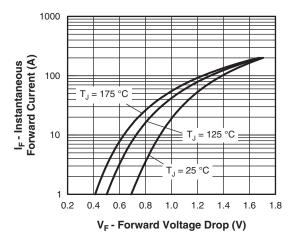


Fig. 1 - Typical Forward Voltage Drop Characteristics

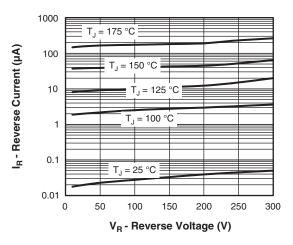


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

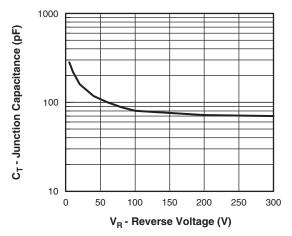


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

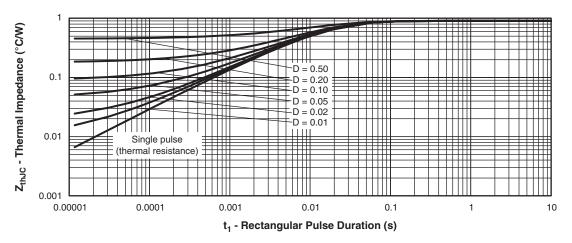


Fig. 4 - Maximum Thermal Impedance  $Z_{\text{thJC}}$  Characteristics

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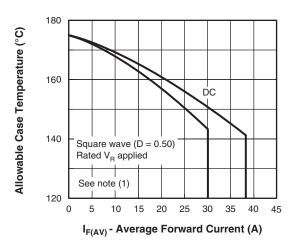


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

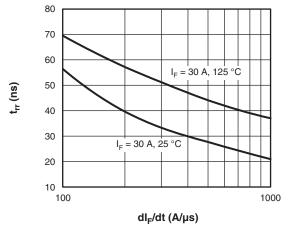


Fig. 6 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

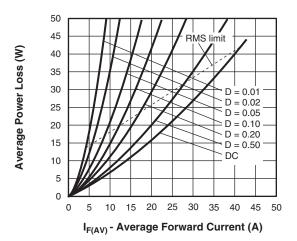


Fig. 7 - Forward Power Loss Characteristics

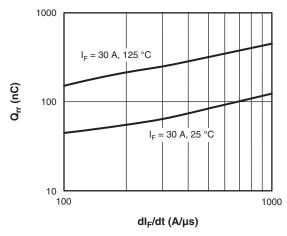


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$ 

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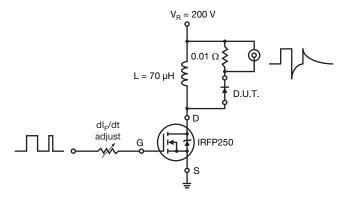
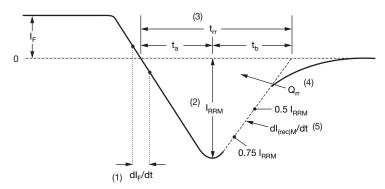


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dI<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_{r}$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  ${\rm Q_{rr}}$  area under curve defined by  ${\rm t_{rr}}$  and  ${\rm I_{RRM}}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dI<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

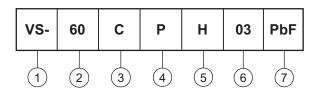
Fig. 10 - Reverse Recovery Waveform and Definitions

## VS-60CPH03PbF, VS-60CPH03-N3

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### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

2 - Current rating (60 = 60 A)

Circuit configuration:

C = Common cathode

4 - Package:

P = TO-247AC (modified)

5 - H = Hyperfast recovery

- Voltage code (03 = 300 V)

7 - Environmental digit:

PbF = Lead (Pb)-free and RoHS compliant

-N3 = Halogen-free, RoHS compliant and totally lead (Pb)-free

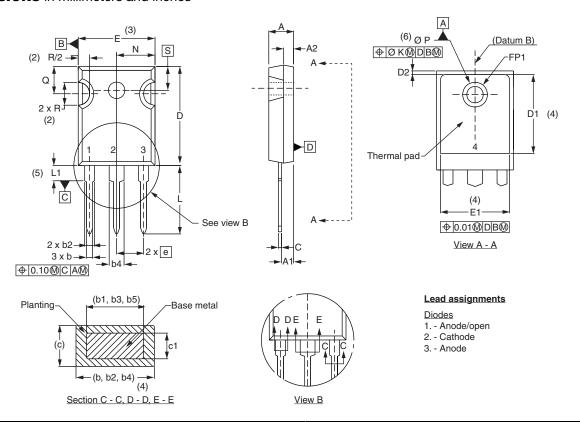
ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-60CPH03PbF	25	500	Antistatic plastic tube				
VS-60CPH03-N3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95223</u>					
Part marking information	TO-247ACPbF	www.vishay.com/doc?95226			
	TO-247AC-N3	www.vishay.com/doc?95007			



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### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	MILLIMETERS INCHES		NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.37	0.065	0.094	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.86	0.015	0.034	
c1	0.38	0.76	0.015	0.030	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.72	-	0.540	-	
е	5.46	BSC	0.215	BSC	
FK	2.54		0.0	10	
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
N	7.62	BSC	0.3		
ΦР	3.56	3.66	0.14	0.144	
ФР1	1	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	1.78	0.216	
S	5.51 BSC		0.217	BSC	

#### **Notes**

- <sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC outline TO-247 with exception of dimension c



### **Legal Disclaimer Notice**

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